

GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

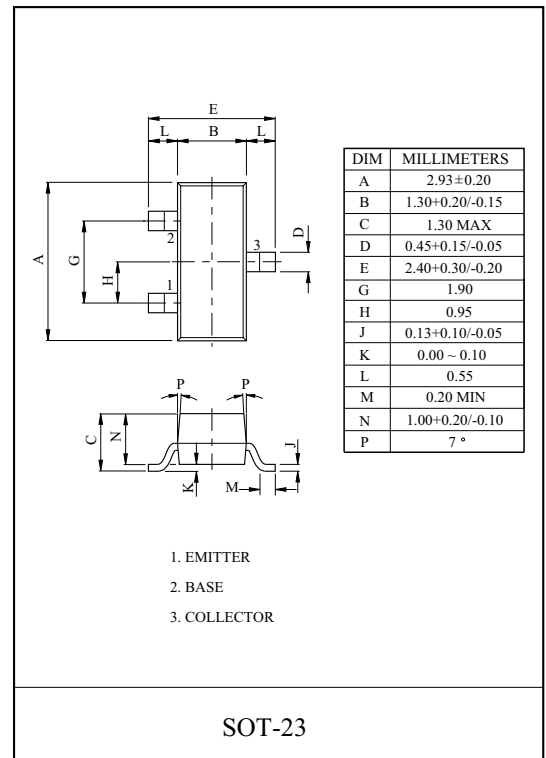
FEATURES

- For Complementary With NPN Type BC846/847/848.

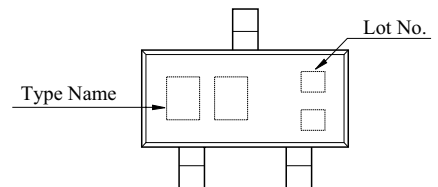
MAXIMUM RATING (Ta=25 °C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	BC856	-80	V
	BC857	-50	
	BC858	-30	
Collector-Emitter Voltage	BC856	-65	V
	BC857	-45	
	BC858	-30	
Emitter-Base Voltage	BC856	-5	V
	BC857	-5	
	BC858	-5	
Collector Current	I_C	-100	mA
Emitter Current	I_E	100	mA
Collector Power Dissipation	P_C^*	350	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C

P_C^* : Package Mounted On 99.5% Alumina 10 × 8 × 0.6mm.



Marking



MARK SPEC

TYPE	BC856A	BC856B	BC857A	BC857B	BC857C	BC858A	BC858B	BC858C
MARK	3A	3B	3E	3F	3G	3J	3K	3L

BC856/7/8

ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB}=-30V, I_E=0$	-	-	-15	nA
DC Current Gain (Note)	BC856	h_{FE}	$V_{CE}=-5V, I_C=-2mA$	125	-	475	
	BC857			125	-	800	
	BC858			125	-	800	
Collector-Emitter Saturation Voltage		$V_{CE(sat)1}$	$I_C=-10mA, I_B=-0.5mA$	-	-0.09	-0.3	V
		$V_{CE(sat)2}$	$I_C=-100mA, I_B=-5mA$	-	-0.25	-0.65	
Base-Emitter Saturation Voltage		$V_{BE(sat)1}$	$I_C=-10mA, I_B=-0.5mA$	-	-0.7	-	V
		$V_{BE(sat)2}$	$I_C=-100mA, I_B=-5mA$	-	-0.9	-	
Base-Emitter Voltage		$V_{BE(ON1)}$	$V_{CE}=-5V, I_C=-2mA$	-0.6	-0.65	-0.75	V
Base-Emitter Voltage		$V_{BE(ON2)}$	$V_{CE}=-5V, I_C=-10mA$	-	-	-0.82	V
Transition Frequency		f_T	$V_{CE}=-5V, I_C=-10mA, f=100MHz$	-	150	-	MHz
Collector Output Capacitance		C_{ob}	$V_{CB}=-10V, I_E=0, f=1MHz$	-	4.5	-	pF
Noise Figure		NF	$V_{CE}=-6V, I_C=-0.2mA$ $R_g=2k\Omega, f=1kHz$	-	2.0	10	dB

NOTE : According to the value of h_{FE} the BC856, BC857, BC858 are classified as follows.

CLASSIFICATION		A	B	C
h_{FE}	BC856	125 ~ 250	220 ~ 475	-
	BC857	125 ~ 250	220 ~ 475	420 ~ 800
	BC858	125 ~ 250	220 ~ 475	420 ~ 800

BC856/7/8

